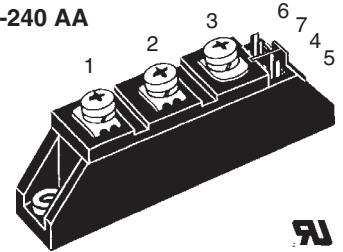


# Thyristor Modules

## Thyristor/Diode Modules

$I_{TRMS} = 2 \times 100 \text{ A}$   
 $I_{TAVM} = 2 \times 64 \text{ A}$   
 $V_{RRM} = 800-1800 \text{ V}$

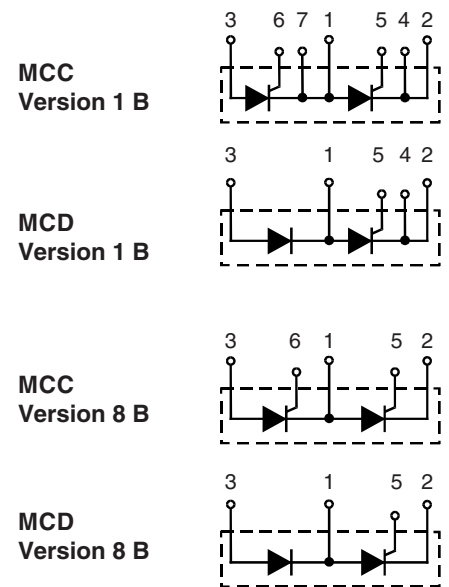
TO-240 AA



| $V_{RSM}$ | $V_{RRM}$ | Type      |               |           |               |     |     |
|-----------|-----------|-----------|---------------|-----------|---------------|-----|-----|
| $V_{DSM}$ | $V_{DRM}$ | Version   |               |           | Version       |     |     |
| V         | V         | 1 B       | 8 B           | 1 B       | 8 B           | 1 B | 8 B |
| 900       | 800       | MCC 56-08 | io1 B / io8 B | MCD 56-08 | io1 B / io8 B |     |     |
| 1300      | 1200      | MCC 56-12 | io1 B / io8 B | MCD 56-12 | io1 B / io8 B |     |     |
| 1500      | 1400      | MCC 56-14 | io1 B / io8 B | MCD 56-14 | io1 B / io8 B |     |     |
| 1700      | 1600      | MCC 56-16 | io1 B / io8 B | MCD 56-16 | io1 B / io8 B |     |     |
| 1900      | 1800      | MCC 56-18 | io1 B / io8 B | MCD 56-18 | io1 B / io8 B |     |     |

| Symbol               | Conditions  | Maximum Ratings   |  |
|----------------------|---|---|--|
| $I_{TRMS}, I_{FRMS}$ | $T_{VJ} = T_{VJM}$  | 100   | A  |
| $I_{TAVM}, I_{FAVM}$ | $T_C = 83^\circ\text{C}; 180^\circ \text{ sine}$  | 64  | A  |
|                      | $T_C = 85^\circ\text{C}; 180^\circ \text{ sine}$  | 60  | A  |
| $I_{TSM}, I_{FSM}$   | $T_{VJ} = 45^\circ\text{C};$<br>$V_R = 0$   | $t = 10 \text{ ms (50 Hz), sine}$<br>$t = 8.3 \text{ ms (60 Hz), sine}$ | 1500<br>1600<br>A<br>A   |
|                      | $T_{VJ} = T_{VJM}$<br>$V_R = 0$   | $t = 10 \text{ ms (50 Hz), sine}$<br>$t = 8.3 \text{ ms (60 Hz), sine}$ | 1350<br>1450<br>A<br>A   |
| $\int i^2 dt$        | $T_{VJ} = 45^\circ\text{C}$<br>$V_R = 0$  | $t = 10 \text{ ms (50 Hz), sine}$<br>$t = 8.3 \text{ ms (60 Hz), sine}$ | 11 200<br>10 750<br>$\text{A}^2\text{s}$<br>$\text{A}^2\text{s}$                         |
|                      | $T_{VJ} = T_{VJM}$<br>$V_R = 0$   | $t = 10 \text{ ms (50 Hz), sine}$<br>$t = 8.3 \text{ ms (60 Hz), sine}$ | 9100<br>8830<br>$\text{A}^2\text{s}$<br>$\text{A}^2\text{s}$                             |
| $(di/dt)_{cr}$       | $T_{VJ} = T_{VJM}$<br>$f = 50 \text{ Hz}, t_p = 200 \mu\text{s}$<br>$V_D = 2/3 V_{DRM}$ | repetitive, $I_T = 150 \text{ A}$                                       | 150<br>$\text{A}/\mu\text{s}$  |
|                      | $I_G = 0.45 \text{ A}$<br>$di_G/dt = 0.45 \text{ A}/\mu\text{s}$                        | non repetitive, $I_T = I_{TAVM}$  | 500<br>$\text{A}/\mu\text{s}$  |
| $(dv/dt)_{cr}$       | $T_{VJ} = T_{VJM};$<br>$R_{GK} = \infty;$ method 1 (linear voltage rise)                | $V_{DR} = 2/3 V_{DRM}$  | 1000<br>$\text{V}/\mu\text{s}$   |
| $P_{GM}$             | $T_{VJ} = T_{VJM};$<br>$I_T = I_{TAVM};$  | $t_p = 30 \mu\text{s}$<br>$t_p = 300 \mu\text{s}$                       | 10<br>5<br>W<br>W  |
| $P_{GAV}$            |   |   | 0.5<br>W   |
| $V_{RGM}$            |   |   | 10<br>V  |
| $T_{VJ}$             |   |   | -40...+125<br>$^\circ\text{C}$   |
| $T_{VJM}$            |   |   | 125<br>$^\circ\text{C}$  |
| $T_{stg}$            |   |   | -40...+125<br>$^\circ\text{C}$   |
| $V_{ISOL}$           | 50/60 Hz, RMS;<br>$I_{ISOL} \leq 1 \text{ mA};$   | $t = 1 \text{ min}$<br>$t = 1 \text{ s}$                                | 3000<br>3600<br>V~<br>V~   |
| $M_d$                | Mounting torque (M5)<br>Terminal connection torque (M5)                                 |   | 2.5-4.0/22-35<br>2.5-4.0/22-35<br>$\text{Nm}/\text{lb.in.}$<br>$\text{Nm}/\text{lb.in.}$ |
| <b>Weight</b>        | Typical including screws  |   | 90<br>g  |

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions



### Features

- International standard package, JEDEC TO-240 AA
- Direct copper bonded  $\text{Al}_2\text{O}_3$  -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873
- Gate-cathode twin pins for version 1B

### Applications

- DC motor control
- Softstart AC motor controller
- Light, heat and temperature control

### Advantages

- Space and weight savings
- Simple mounting with two screws
- Improved temperature and power cycling
- Reduced protection circuits

| Symbol             | Conditions  | Characteristic Values |                  |
|--------------------|---|-----------------------|------------------|
| $I_{RRM}, I_{DRM}$ | $T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$  | 5                     | mA               |
| $V_T, V_F$         | $I_T/I_F = 200 \text{ A}; T_{VJ} = 25^\circ\text{C}$  | 1.57                  | V                |
| $V_{T0}$           | For power-loss calculations only ( $T_{VJ} = 125^\circ\text{C}$ )   | 0.85                  | V                |
| $r_T$              |   | 3.7                   | m $\Omega$       |
| $V_{GT}$           | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$  | 1.5                   | V                |
|                    | $T_{VJ} = -40^\circ\text{C}$  | 1.6                   | V                |
| $I_{GT}$           | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$  | 100                   | mA               |
|                    | $T_{VJ} = -40^\circ\text{C}$  | 200                   | mA               |
| $V_{GD}$           | $T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$   | 0.2                   | V                |
| $I_{GD}$           |   | 10                    | mA               |
| $I_L$              | $T_{VJ} = 25^\circ\text{C}; t_p = 10 \mu\text{s}; V_D = 6 \text{ V}$<br>$I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu\text{s}$  | 450                   | mA               |
| $I_H$              | $T_{VJ} = 25^\circ\text{C}; V_D = 6 \text{ V}; R_{GK} = \infty$   | 200                   | mA               |
| $t_{gd}$           | $T_{VJ} = 25^\circ\text{C}; V_D = 1/2 V_{DRM}$<br>$I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu\text{s}$  | 2                     | $\mu\text{s}$    |
| $t_q$              | $T_{VJ} = T_{VJM}; I_T = 150 \text{ A}, t_p = 200 \mu\text{s}; -di/dt = 10 \text{ A}/\mu\text{s}$<br>$V_R = 100 \text{ V}; dv/dt = 20 \text{ V}/\mu\text{s}; V_D = 2/3 V_{DRM}$ | typ. 150              | $\mu\text{s}$    |
| $Q_S$              | $T_{VJ} = T_{VJM}; I_T, I_F = 50 \text{ A}, -di/dt = 3 \text{ A}/\mu\text{s}$   | 100                   | $\mu\text{C}$    |
| $I_{RM}$           |   | 24                    | A                |
| $R_{thJC}$         | per thyristor/diode; DC current per module  | 0.45                  | K/W              |
| $R_{thJK}$         | per thyristor/diode; DC current per module  | 0.225                 | K/W              |
|                    | other values see Fig. 8/9   | 0.65                  | K/W              |
|                    |   | 0.325                 | K/W              |
| $d_s$              | Creepage distance on surface  | 12.7                  | mm               |
| $d_A$              | Strike distance through air   | 9.6                   | mm               |
| $a$                | Maximum allowable acceleration  | 50                    | m/s <sup>2</sup> |

Optional accessories for module-type MCC 56 version 1 B  
 Keyed gate/cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red  
 Type **ZY 200L** (L = Left for pin pair 4/5) } UL 758, style 1385,  
 Type **ZY 200R** (R = right for pin pair 6/7) } CSA class 5851, guide 460-1-1

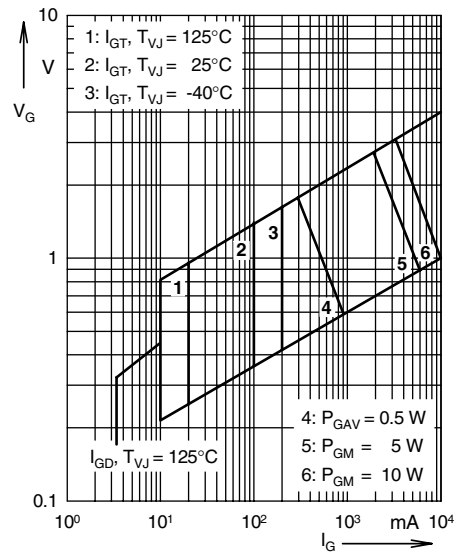


Fig. 1 Gate trigger characteristics

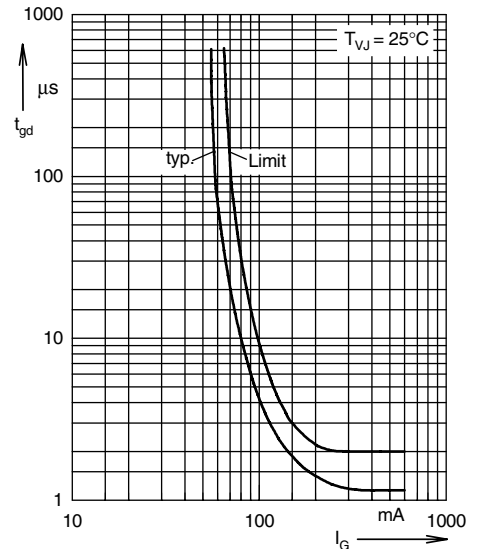
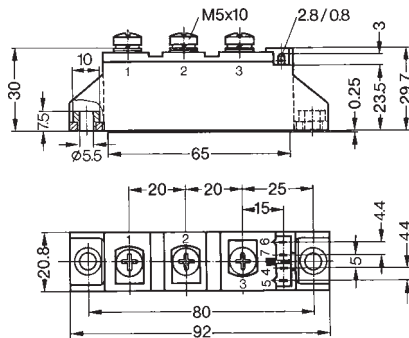


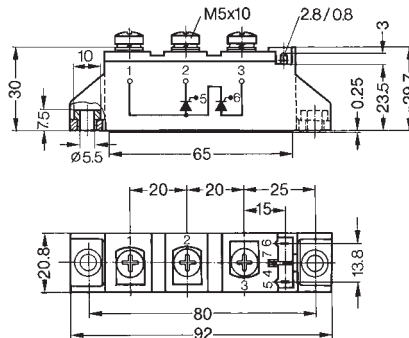
Fig. 2 Gate trigger delay time

**Dimensions in mm (1 mm = 0.0394")**

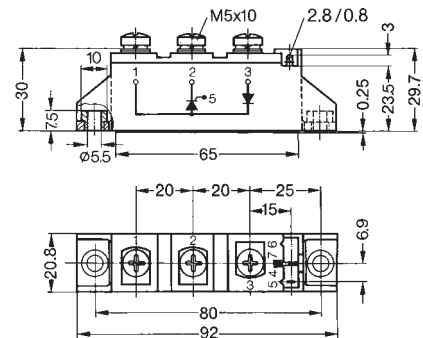
**MCC / MCD / MDC Version 1 B**



**MCC Version 8 B**



**MCD Version 8 B**



Version 1 or 8 without B in type designation = without insert in mount holes

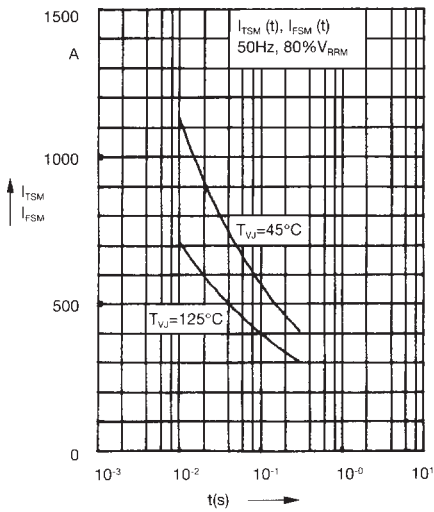


Fig. 3 Surge overload current  
 $I_{TSM}$ ,  $I_{FSM}$ : Crest value, t: duration

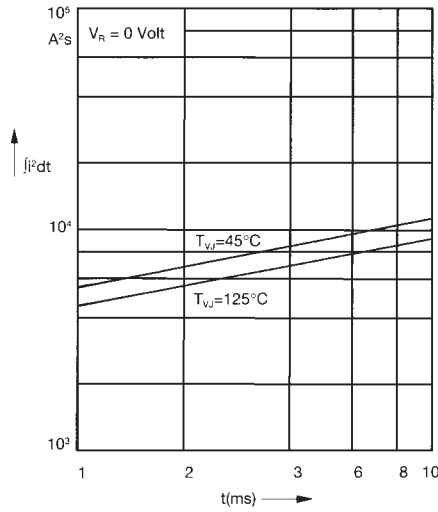


Fig. 4  $\int i^2 dt$  versus time (1-10 ms)

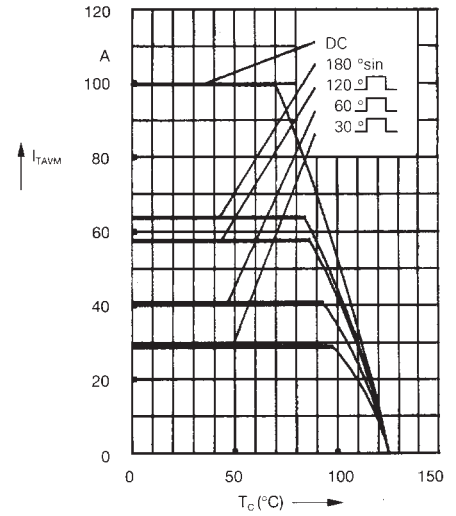


Fig. 4a Maximum forward current at case temperature

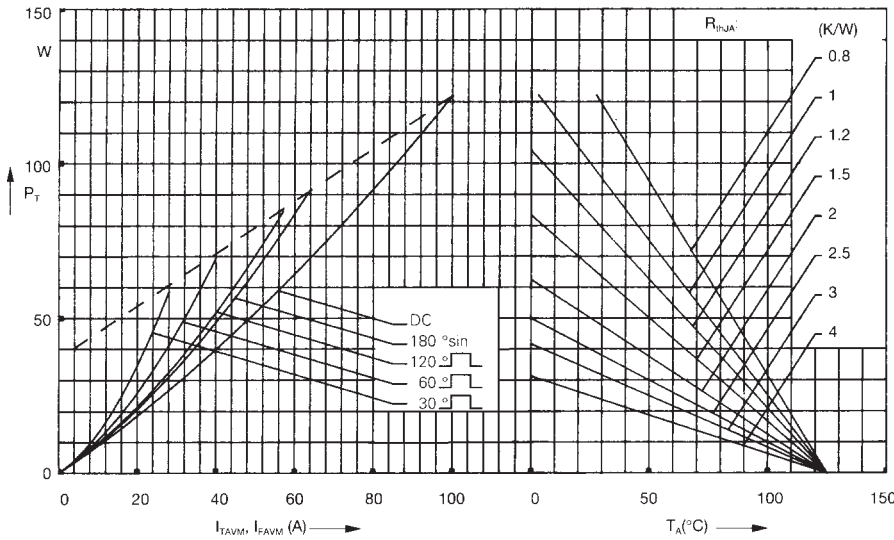


Fig. 5 Power dissipation versus on-state current and ambient temperature (per thyristor or diode)

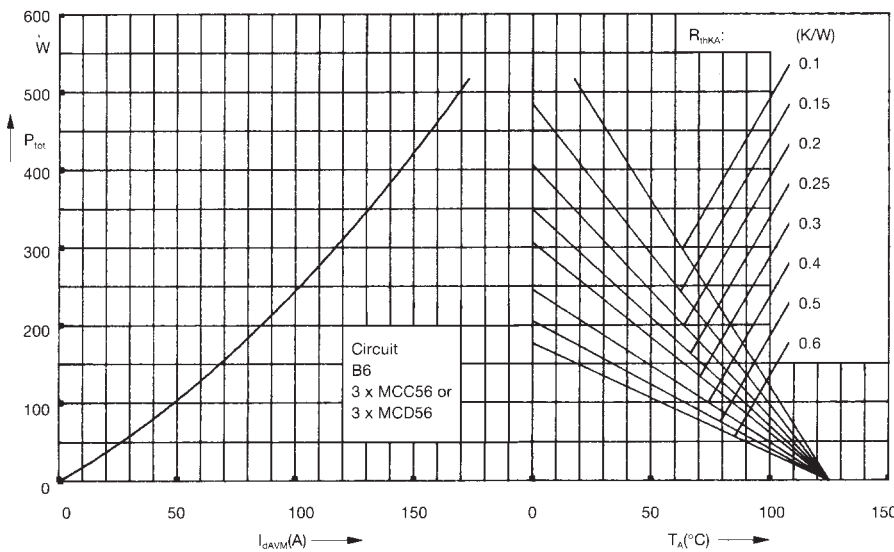


Fig. 6 Three phase rectifier bridge:  
Power dissipation versus direct output current and ambient temperature

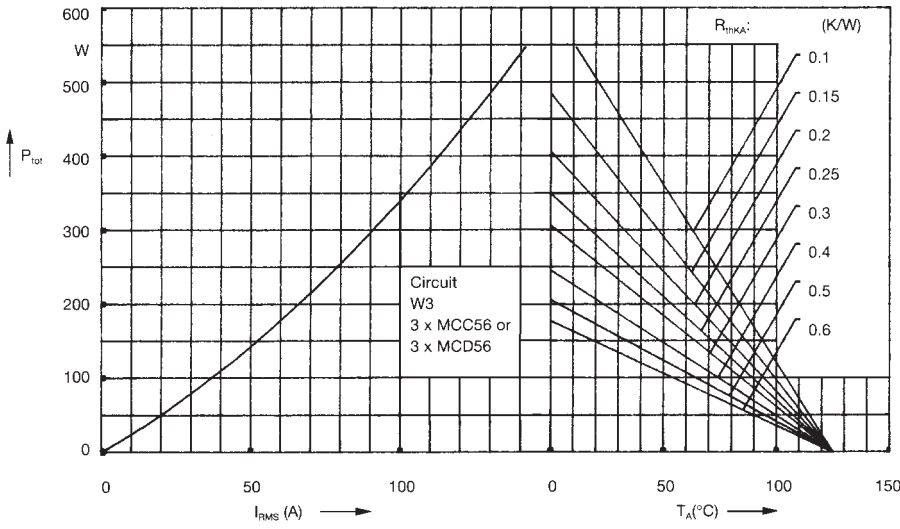


Fig. 7 Three phase AC-controller:  
Power dissipation versus RMS  
output current and ambient  
temperature

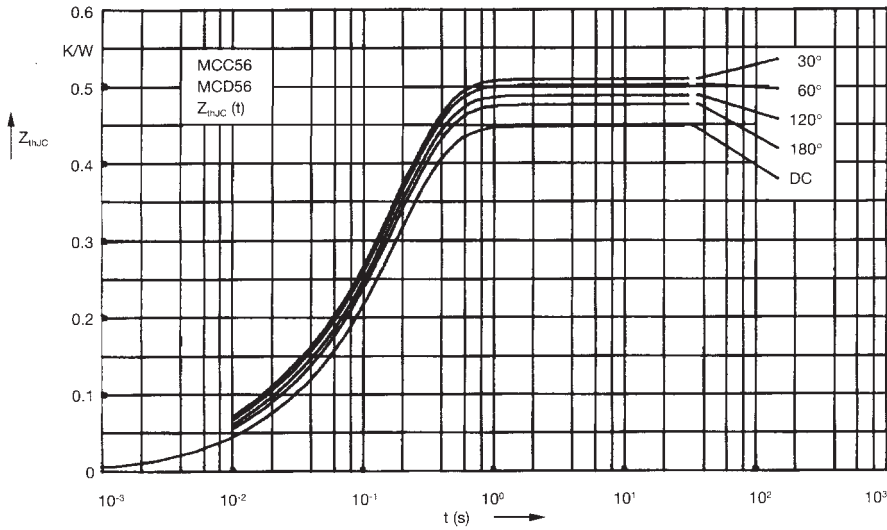


Fig. 8 Transient thermal impedance  
junction to case (per thyristor or  
diode)

$R_{thJC}$  for various conduction angles d:

| d    | $R_{thJC}$ (K/W) |
|------|------------------|
| DC   | 0.45             |
| 180° | 0.47             |
| 120° | 0.49             |
| 60°  | 0.505            |
| 30°  | 0.52             |

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.014           | 0.015     |
| 2 | 0.026           | 0.0095    |
| 3 | 0.41            | 0.175     |

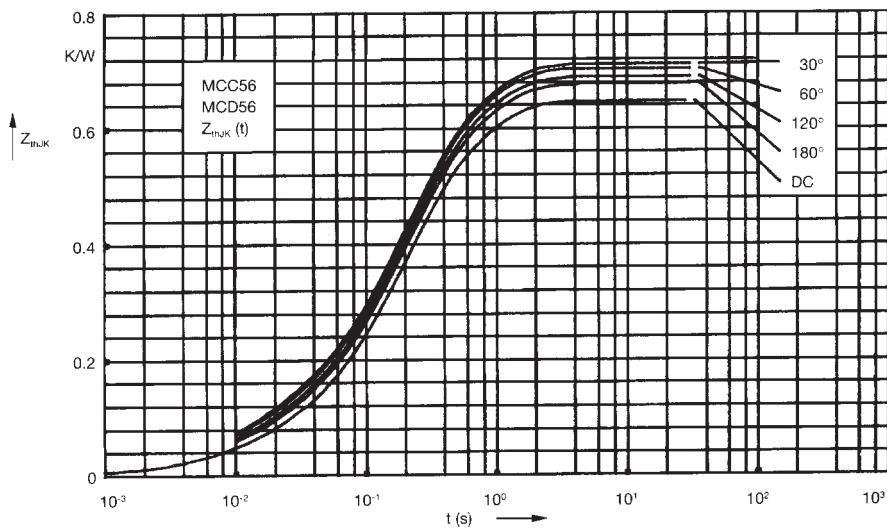


Fig. 9 Transient thermal impedance  
junction to heatsink (per thyristor  
or diode)

$R_{thJK}$  for various conduction angles d:

| d    | $R_{thJK}$ (K/W) |
|------|------------------|
| DC   | 0.65             |
| 180° | 0.67             |
| 120° | 0.69             |
| 60°  | 0.705            |
| 30°  | 0.72             |

Constants for  $Z_{thJK}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.014           | 0.015     |
| 2 | 0.026           | 0.0095    |
| 3 | 0.41            | 0.175     |
| 4 | 0.2             | 0.67      |